

Supporting Information

Solution-processed and self-powered photodetector in vertical architecture using mixed-halide perovskite for highly sensitive UVC detection

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Calculation of the trap density

The trap densities of the electron/hole-only device were calculated using the following equation:

$$n_{traps} = \frac{2\varepsilon_0\varepsilon}{qV_{TFL}L^2}$$

where ε_0 is the vacuum permittivity ($\varepsilon_0 = 8.8542 \times 10^{-12}$), ε is the dielectric constant of perovskite ($\varepsilon = 25$), q is the elementary charge ($q = 1.6022 \times 10^{-19}$ C), L is the thickness of perovskite ($L = 580$ nm) and V_{TFL} is the trap-filled limit voltages of the electron/hole-only device which determined by I-V curve in dark condition. V_{TFL} of the hole-only device and electron-only device were 0.195 V and 0.45 V, respectively. According to the above values, the hole and trap densities (n_{traps}) of devices were estimated equal to 1.6×10^{15} cm⁻³ and 3.6×10^{15} cm⁻³.

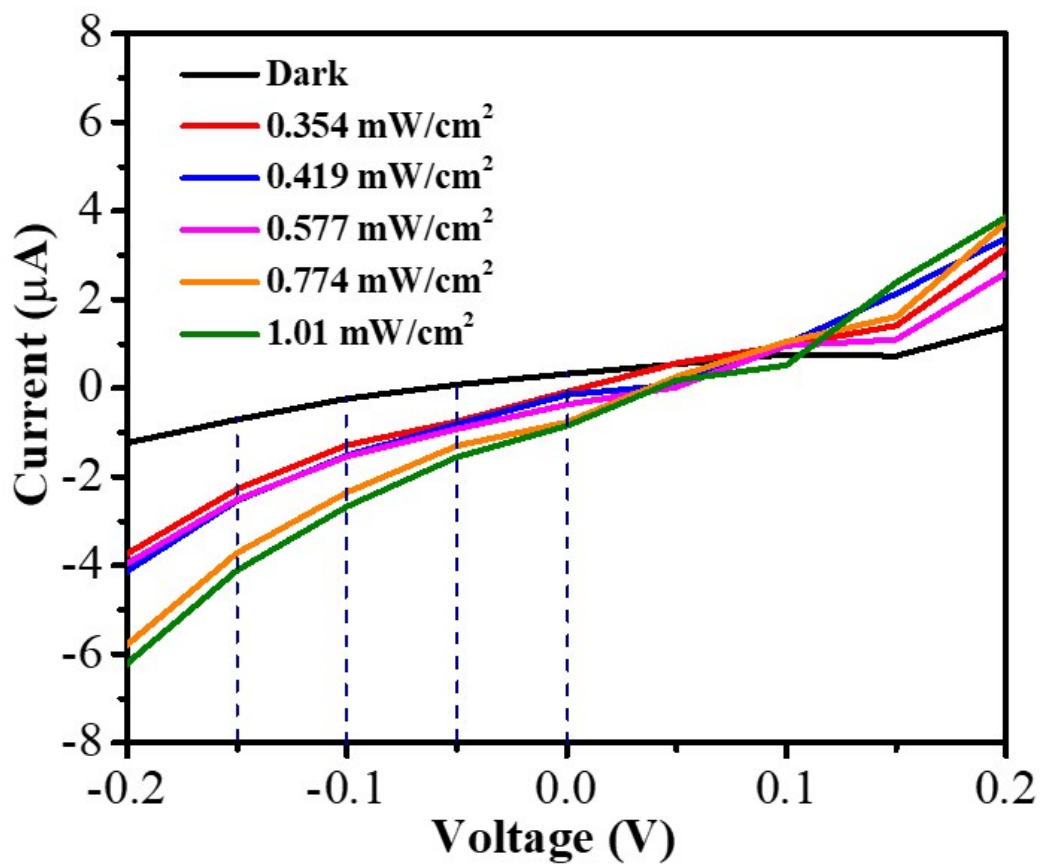


Fig. S1 I - V characteristics of the photodetector measured under dark and different light intensities at 254 nm light and 0 V bias voltage.

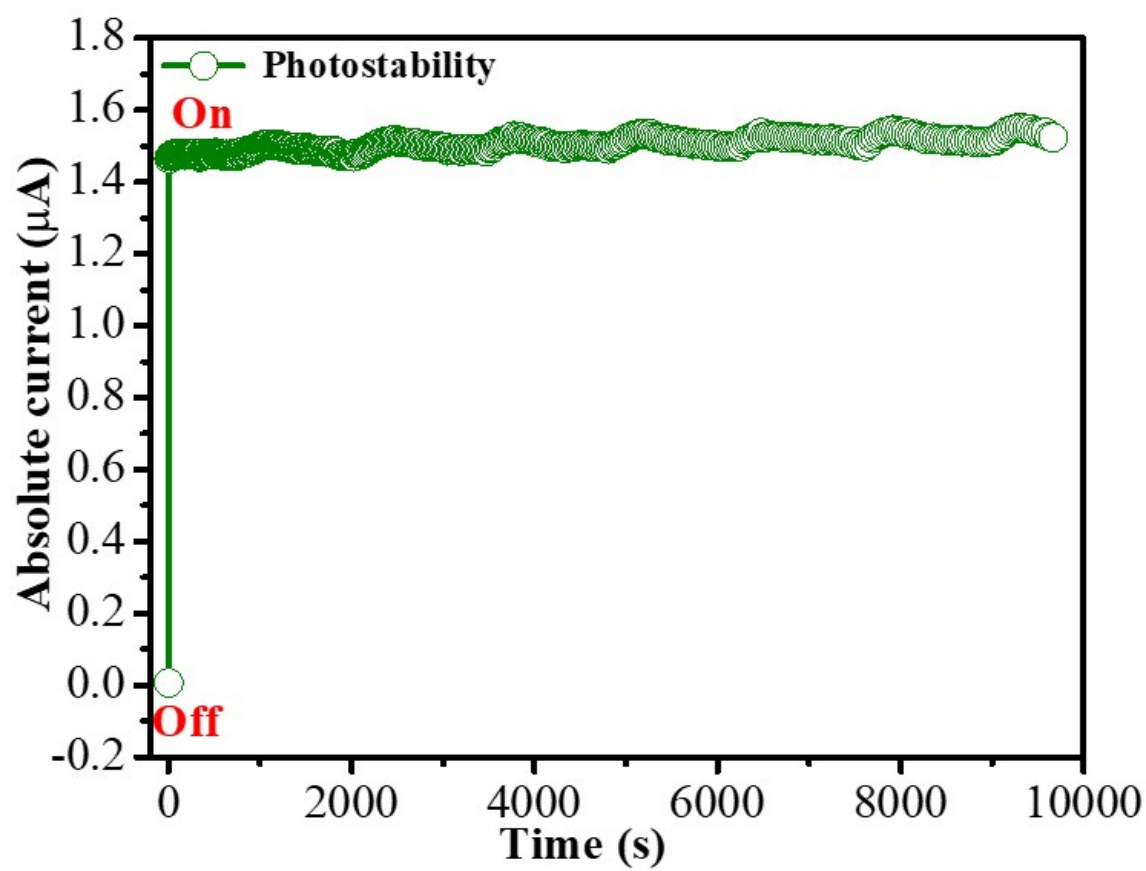


Fig. S2 The photostability of photodetector measured under 254nm-UVC light illumination.

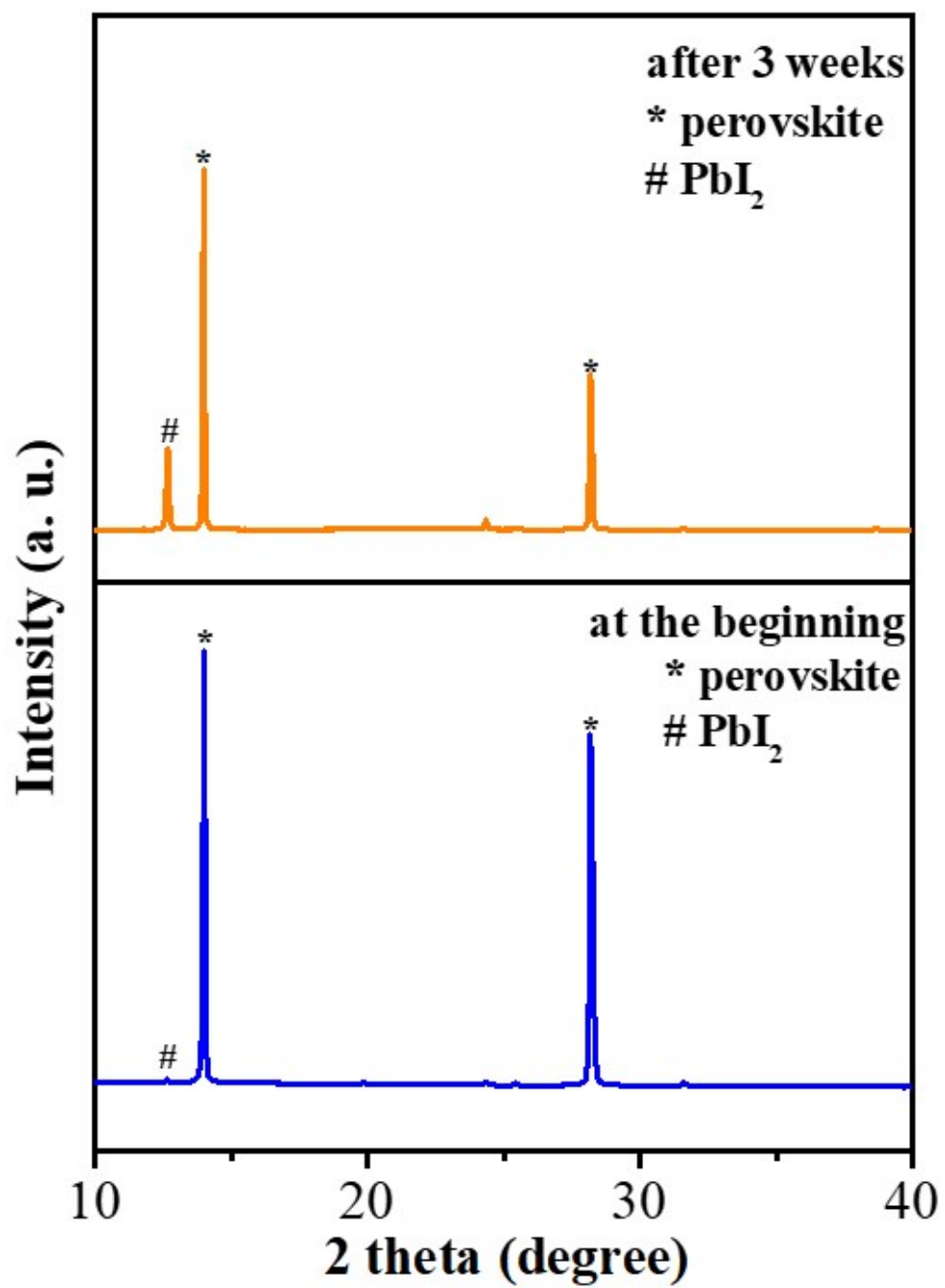


Fig. S3 The XRD patterns of perovskite film on quartz at the beginning and after 3 weeks

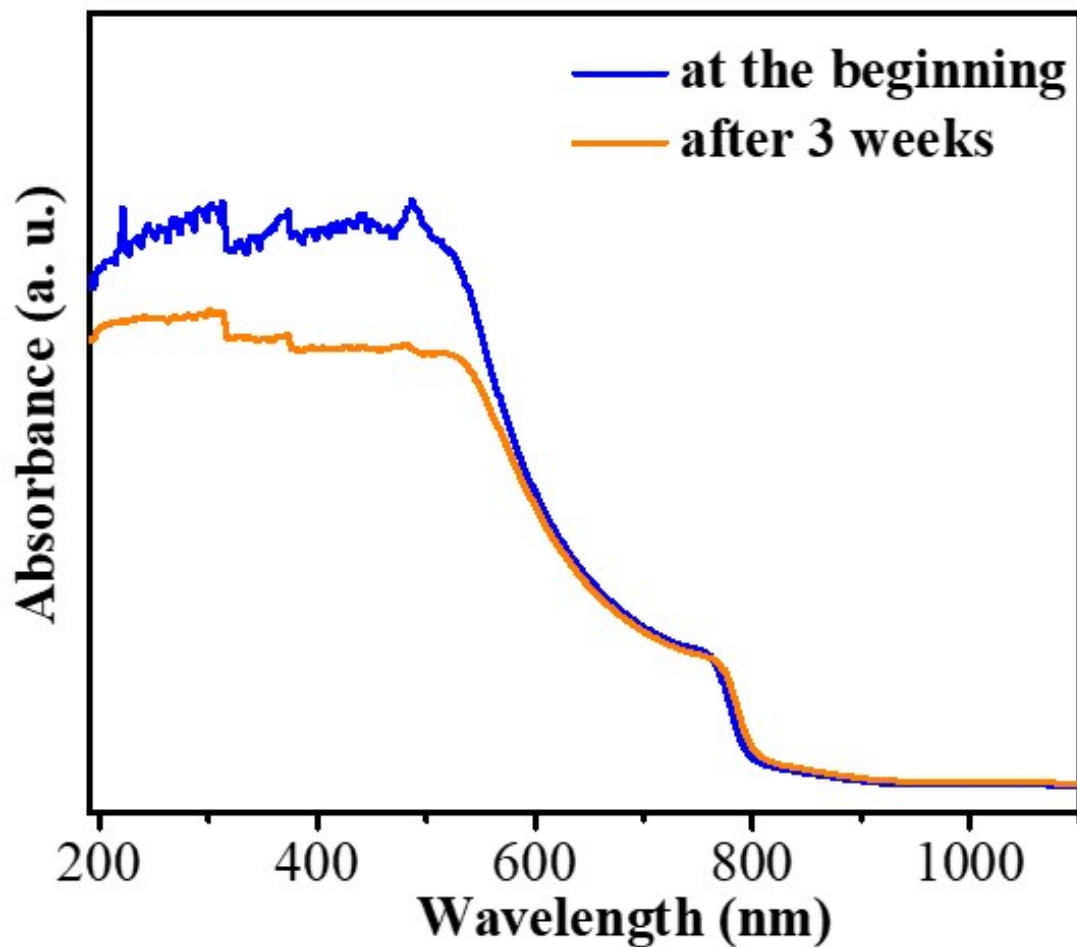


Fig. S4 The UV-vis spectra of perovskite film on quartz at the beginning and after 3 weeks

Table S1. The performance parameters of the photodetector with different bias voltages

Light intensity (mW/cm ²)	Voltage (V)	Responsivity (mA/W)	Detectivity (Jones)	EQE (%)
0.774	0	52.36	4.23×10^{11}	25.61
0.774	-0.05	50.07	4.37×10^{10}	24.49
0.774	-0.1	51.39	2.33×10^{10}	25.13
0.774	-0.15	57.28	1.72×10^{10}	28.01
0.774	-0.2	76.28	1.73×10^{10}	37.31

Table S2. The performance parameters of the photodetector with different light intensities

Light intensity (mW/cm²)	Voltage (V)	Responsivity (mA/W)	Detectivity (Jones)	EQE (%)
1.01	0	44.63	3.94×10^{11}	21.83
0.774	0	52.68	4.65×10^{11}	25.76
0.577	0	47.78	4.22×10^{11}	23.37
0.419	0	42.72	3.77×10^{11}	20.89
0.354	0	44.08	3.89×10^{11}	21.56